

isc N-Channel MOSFET Transistor

IXTP50N20PM

FEATURES

- · Drain Source Voltage-
- : V_{DSS}= 200V(Min)
- Static drain-source on-resistance
 - : RDS(on) \leq 60m Ω @V_{GS}=10V
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



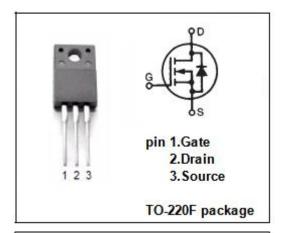
- DC/DC Converter
- · Ideal for high-frequency switching and synchronous rectification

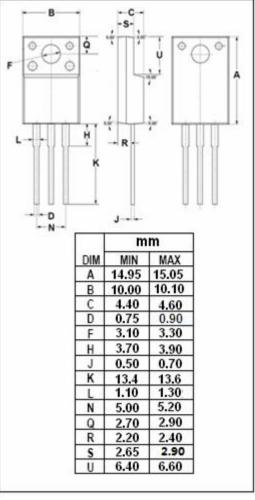
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|------------------------------|--------------|--|
| V _{DSS} | Drain-Source Voltage | 200 | V | |
| V_{GS} | Gate-Source Voltage | ±20 V | | |
| l _D | Drain Current-Continuous 50 | | А | |
| I _{DM} | Drain Current-Single Pulsed 120 | | Α | |
| P _D | Total Dissipation @T _C =25℃ | 90 | W | |
| Tj | Operating Junction Temperature | Junction Temperature -55~175 | | |
| T _{stg} | Storage Temperature | -55~175 | $^{\circ}$ C | |
| | | | | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|----------------------|-------------------------------------|------|------|
| $R_{\text{th(j-c)}}$ | Junction-to-case thermal resistance | 1.66 | °C/W |







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|---------------------|--------------------------------|--|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; ID =250 μ A | 200 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} ; ID =250 μ A | 2.5 | 5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D = 25A | | 60 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V;V _{DS} =0V | | ±100 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = 200V; V _{GS} = 0V | | 25 | - μΑ |
| | | V _{DS} = 200V; V _{GS} = 0V;T _J =125°C | | 250 | |
| VsD | Diode forward voltage | I _F = 50A; V _{GS} = 0V | | 1.5 | V |



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